

US1XW SERIES

SURFACE MOUNT ULTRAFAST RECOVERY RECTIFIER

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US1AW THRU US1MW

SURFACE MOUNT ULTRAFAST RECOVERY RECTIFIER



康比電子
HORNBY ELECTRONIC

REVERSE VOLTAGE: 50 to 1000 VOLTS

FORWARD CURRENT: 1.0 AMPERE

FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-O
- For surface mounted applications
- Low profile package
- Easy pick and place
- Built-in strain relief
- Ultrafast recovery times for high efficiency
- High temperature soldering : 250°C /10 seconds at terminals

MECHANICAL DATA

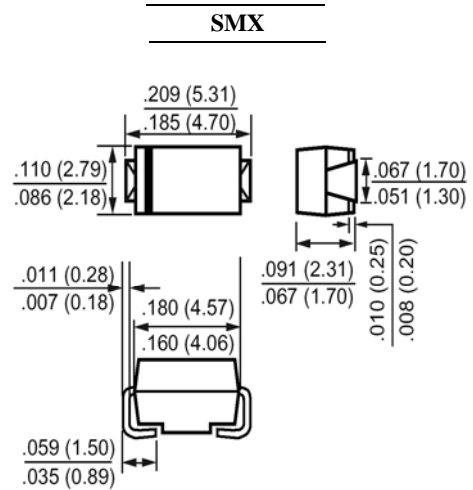
Case: Molded plastic, SMX

Terminals: Solder plated, solderable per MIL-STD-750, method 2026 guaranteed

Polarity: Color band denotes cathode end

Packaging: 12mm tape per EIA STD RS-481

Weight: 0.002 ounce, 0.064 gram



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

	Symbols	US1AW	US1BW	US1DW	US1GW	US1JW	US1KW	US1MW	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current at $T_L=100^\circ\text{C}$	$I_{(AV)}$	1.0							Amp
Peak Forward Surge Current, 8.3ms single half-sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	30							Amp
Maximum Forward Voltage at 1.0A	V_F	1.0		1.3		1.7			Volts
Maximum Reverse Current at $T_A=25^\circ\text{C}$	I_R	5.0							μAmp
at Rated DC Blocking Voltage $T_A=100^\circ\text{C}$		100							
Typical Junction Capacitance (Note 1)	C_J	17							pF
Typical Thermal Resistance (Note 2)	$R_{\theta JL}$	30							$^\circ\text{C/W}$
Maximum Reverse Recovery Time (Note 3)	T_{RR}	50				75			nS
Operating Junction Temperature Range	T_J	-55 to +150							$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-55 to +150							$^\circ\text{C}$

NOTES:

1- Measured at 1 MHz and applied reverse voltage of 4.0 VDC.

2- Thermal resistance from junction to lead mounted on P.C.B. with 0.3 x 0.3" (8.0 x 8.0mm) copper pad areas

3- Reverse Recovery Test Conditions: $I_F=.5\text{A}$, $I_R=1\text{A}$, $I_{RR}=.25\text{A}$.

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RATINGS AND CHARACTERISTIC CURVES

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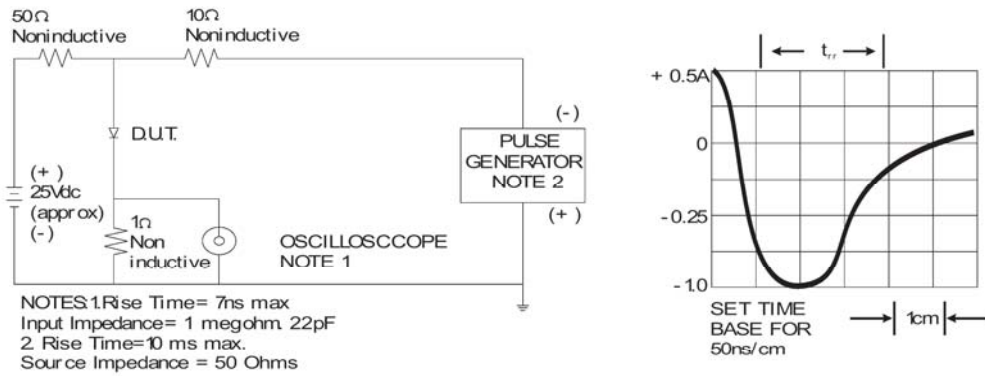


Fig. 1-REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

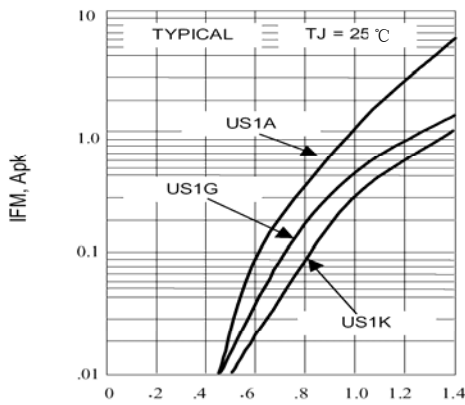


Fig. 2-FORWARD CHARACTERISTICS

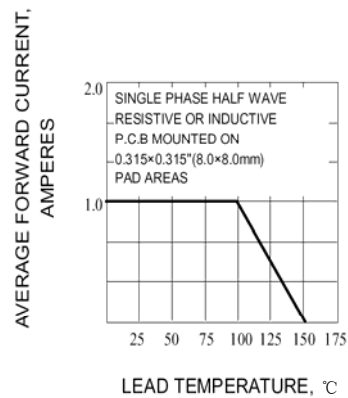


Fig. 3-FORWARD CURRENT DERATING CURVE

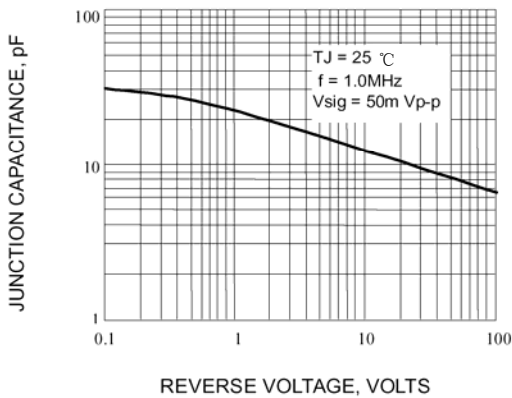


Fig. 4-TYPICAL JUNCTION CAPACITANCE

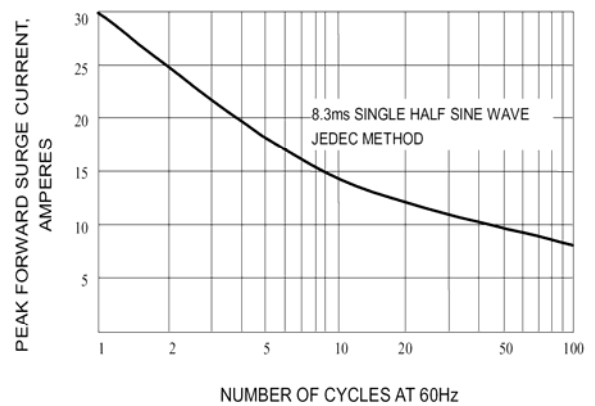


Fig. 5-PEAK FORWARD SURGE CURRENT